

Red shift properties, crystal field theory and nephelauxetic effect on Mn⁴⁺-doped SrMgAl_{10-y}Ga_yO₁₇ red phosphor for plant growth LED light

1. Introduction

China is an agricultural country, and plant cultivation plays an important role in agricultural production. Conventional agriculture suffers from harsh environment such as frost, cloudy, droughts and rainstorms, resulting in a reduced yield, which cannot satisfy people's needs. In recent years, indoor plant cultivation has caused a lot of concern for constructing a suitable and stable growing environment for plant growth. Light source is an essential condition in all process of plant growth including branching, flowering, and fruiting¹⁻³. Light energy can be converted into chemical energy by photosynthesis of plant pigments. Chlorophyll A, chlorophyll B, phytochrome P_R and phytochrome P_{FR} are four main plant pigments which mainly absorb blue (400-500 nm), red (600-700 nm) and far-red (700-750 nm) lights. The traditional light source for indoor plant cultivation are mainly including incandescent lamps, high-pressure sodium lamps and fluorescent lamps, but they suffer from the disadvantages such as high energy consumption, short lifetime and spectral mismatch. Therefore, phosphor conversion light-emitting diode has gradually become the mainstream device in indoor plant culture for their saving of energy, long lifetime, spectral match and environment friendly. Phosphors play an indispensable role in LED devices which determines the photoluminescence properties of the devices

directly. Meanwhile, plant growth LEDs need to work for a long time under high power, therefore, it is important to design and synthesis the phosphors with proper spectral emission and excellent thermal stability⁴⁻⁶.

Based on this situation, many phosphors had been investigated and discussed to fulfil the light requirements of plant growth. The commercial phosphor $\text{Y}_3\text{Al}_5\text{O}_{12}:\text{Ce}^{3+}$ is widespread using in white LEDs, but it is not suitable for plant growth LEDs because mismatched spectral bands. As we all know, red and far-red lights have beneficial in promoting plant growth and biomass accumulation. Most of the researches on plant growth lighting focus on the red and blue emitting materials, but the far-red emission phosphor have little reported while far-red band is also a crucial part. Nowadays, the main commercial red phosphor are Eu^{2+} -doped nitrides likes $(\text{Ca},\text{Sr})\text{AlSiN}_3:\text{Eu}^{2+}$ ⁷⁻⁹ and $(\text{Ca},\text{Sr})_2\text{Si}_5\text{N}_8:\text{Eu}^{2+}$ ^{10, 11}. However, the preparation conditions for these phosphors are harsh, they usually need high temperature (>1800°C) and high pressure in oxygen-free environment. The critical preparation requirement increases the cost of the product and limits their large-scale use in agricultural industry. Another red phosphor is Mn^{4+} -doped fluoride, such as $\text{K}_2\text{TiF}_6:\text{Mn}^{4+}$ ¹² and $\text{K}_2\text{SiF}_6:\text{Mn}^{4+}$ ¹³. The preparation of such materials is commonly used HF which is harmful to environment, and the product is unstable and easily decomposed in moist environment due to the existence of $[\text{MnF}_6]^{2-}$ clusters. As an alternative, Mn^{4+} -doped oxides have received extensive attention from researchers, for series advantages of them such as attractive photoluminescence properties, high stability, low cost and eco-friendliness¹⁴. Many Mn^{4+} -doped oxides red emission

phosphors have been investigated and reported. Zhou *et al.*¹⁵ summarized and described the characteristic emission lines of Mn⁴⁺ about Mn⁴⁺-activated luminescent materials systematically. The excitation wavelength of Mn-activated phosphors locates in the n-UV and blue region of 200-500 nm, and could be efficiently excited by commercialized n-UV and blue chips. Most importantly, due to the characteristic transitions of ${}^2E_g \rightarrow {}^4A_2$, the emission band of these phosphors is located at red and far-red regions, matching well with the absorption of plant pigments. Other Mn⁴⁺-doped oxides such as SrLaAlO₄¹⁶, La₂LiSbO₆¹⁷, Gd₂ZnTiO₆¹⁸ has also been reported for plant cultivation with characteristic red emission of Mn⁴⁺. Nonetheless, they still have many shortcomings such as low quantum efficiency, poor thermal stability and lack far-red band emission. Meanwhile, Mn⁴⁺-doped Ca₁₄(Ga/Al)₁₀Zn₆O₃₅^{19, 20} red phosphors were widely investigated by many researchers for their bright red emission, high quantum yield and good thermal stability.

Solid solution effect plays a key role on the design and preparation in Mn⁴⁺-doped Ca₁₄(Ga/Al)₁₀Zn₆O₃₅ phosphors. There are three conditions on solid solution effect can be described as similar ion radius, analogical structure and electronegativity alike. Zhao *et al.*²¹ and Zhou *et al.*²² reported the lattice site can be adjust by replacing Ga³⁺ with Al³⁺ in Ca₁₄Ga_{10-x}Al_xZn₆O₃₅ phosphor, for the lattice position of Ga³⁺ or Al³⁺ can be substituted by the activator, leading enhanced photoluminescence intensity and quantum efficiencies of samples. Analogously, Qiao *et al.*²³ reported a single-phased white emission (Ca_{9-x}Sr_x)MgK(PO₄)₇:Eu²⁺ phosphor

though tuning of the compositions and multiple activator sites, and the thermal stability increased significantly via Sr^{2+} to replace Ca^{2+} . Similar improved quantum efficiency and thermal stability results were also seen in the in blue-emitting $\text{Ba}_{2-x}\text{Sr}_x\text{SiO}_4:\text{Ce}^{3+}$ phosphor²⁴. Take inspiration from these literatures, we assumed Ga^{3+} to replace Al^{3+} in $\text{SrMgAl}_{10}\text{O}_{17}:\text{Mn}^{4+}$ phosphor in order to enhance its luminescence properties. As far as we know, there is no similar literature has been reported.

In this study, a novel Mn^{4+} -doped $\text{SrMgAl}_{10-y}\text{Ga}_y\text{O}_{17}$ red phosphor with tunable emission properties and great improved intensity are discovered, which synthesized via high-temperature solid-state method in atmospheric environment. The phase structure, photoluminescence (PL) and photoluminescence excitation (PLE) spectra, absorption spectra, quantum yield, lifetime decay curves and electroluminescence were investigated in details. Finally, the LED device combined with blue chip and the as-obtained phosphors show bright blue and red emission which match with the plant absorption spectrum well, indicates this phosphor can be a candidate for indoor plant growth light.

2. Experimental section

The raw materials were SrCO_3 (99.99%), MgO (99.99%), Al_2O_3 (99.99%), Ga_2O_3 (99.99%) and MnCO_3 (99.99%) which bought from Aladdin without further purification, in which different contents of H_3BO_3 (AR) (1% wt, 2% wt, 3% wt, 4% wt, 5% wt) acted as flux in the reaction process to get the ideal samples without impurities. All reagents were weighed according to the stoichiometric ratio, put into

an agate mortar and dropped with a certain amount of absolute ethyl alcohol to mix the materials up uniformly. These powders were ground for 30 minutes, and then transferred into corundum crucibles. They were put into a tube furnace preheated at 800 °C for 2 hours and sintered at 1500 °C in ambient atmosphere for 5 hours with a heating rate of 5 °C/min in the whole process. The tube furnace was turned off to have the samples cool down to room temperature naturally. Finally the $\text{SrMgAl}_{10}\text{O}_{17}:\text{xMn}^{4+}$ ($\text{x} = 0.1\%, 0.3\%, 0.5\%, 1.0\%, 1.5\%, 2.0\%$) and $\text{SrMgAl}_{10-y}\text{Ga}_y\text{O}_{17}:\text{Mn}^{4+}$ ($\text{y} = 1, 2, 3, 4, 5, 6$) samples were obtained then reground to fine powders for further characterizations.

The X-ray powder diffraction (XRD) patterns were measured range from 20° to 90° by a diffractometer (D/SHIMADZU-6000, Japan) which equipped with Cu-K α radiation ($\lambda=1.5406 \text{ \AA}$). The scanning rate is 6°/min and operating voltage and current are 40 kV and 40 mA. F-4700 fluorescence spectrophotometer (Hitachi, Japan) equipped with a 150W Xe lamp was used to obtain the photoluminescence excitation (PLE) and photoluminescence (PL) spectra. The UV-vis absorption spectra were tested on U-3310 spectrophotometer (Hitachi, Japan). Temperature-dependent PL spectra were measured using F-7000 Spectro-photometer (Hitachi, Japan) by changing the testing temperature from 298K to 473K. FLS 1000 fluorescence spectrometer (Edinburgh, UK) was used to get the lifetime curves and quantum efficiency.

3. Results and discussion

First of all, H_3BO_3 was chosen to as flux in the synthesis process, as shown in

Fig.S1 (a), the XRD pattern of samples exhibit impurity phase of SrAl_2O_4 before the content of H_3BO_3 below 2 wt %, after that the XRD represent pure phase of $\text{SrMgAl}_{10}\text{O}_{17}$ with the standard card of PDF#26-0879. Considering the photoluminescence excitation (PLE) and photoluminescence (PL) spectra of samples with different content of flux, the emission intensity reached the maximum when 2 wt % H_3BO_3 participates in the synthesis reaction, thus this condition was selected in the following section.

3.1 Structure and phase characterization

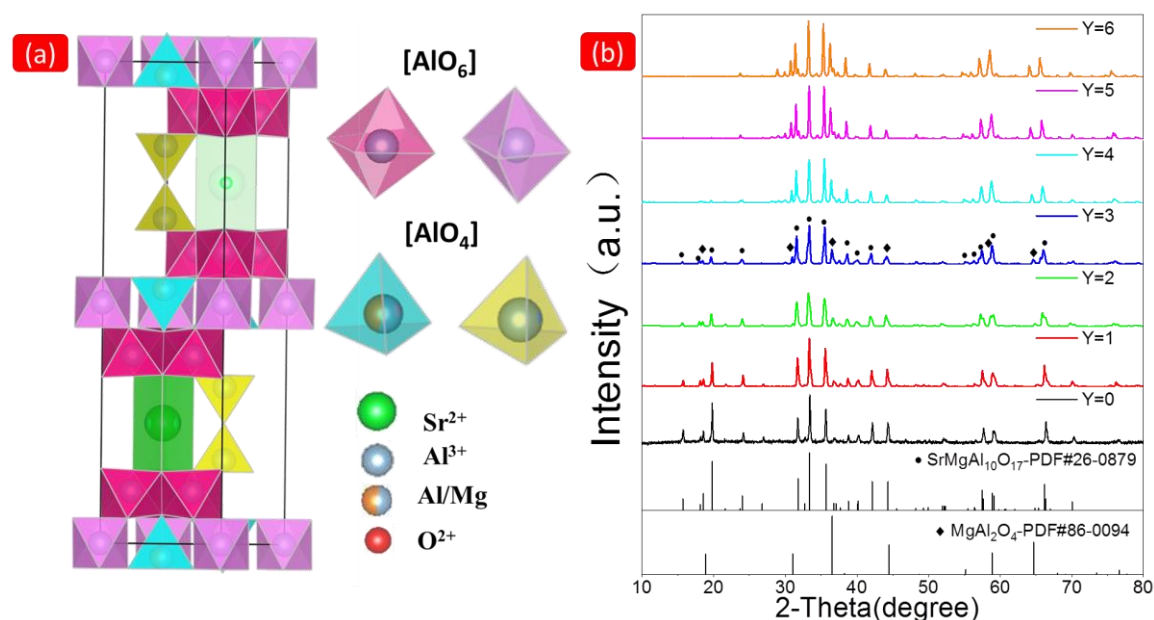


Fig. 1 (a) The crystal structure of $\text{SrMgAl}_{10}\text{O}_{17}$ host, the coordination environment of the octahedron $[\text{AlO}_6]$ and tetrahedron $[\text{AlO}_4]$; (b) The XRD patterns of $\text{SrMgAl}_{10-y}\text{Ga}_y\text{O}_{17}:\text{Mn}^{4+}$ ($y = 0, 1, 2, 3, 4, 5, 6$) phosphors.

The $\text{SrMgAl}_{10}\text{O}_{17}$ crystal belongs to $P6_3/mmc$ space group with hexagonal structure as shown in Fig.1 (a). It's worth noting that asymmetric part of the unit cell contains four independent sites of Al^{3+} which be written as two $[\text{AlO}_6]$ and two $[\text{AlO}_4]$. One of them in tetrahedron $[\text{AlO}_4]$ shares the position with Mg^{2+} randomly. In

generally, activator ion Mn^{4+} prefer to replace Al^{3+} in octahedron $[\text{AlO}_6]$ position for similar ionic radius of Mn^{4+} ($r = 0.530$ Å, CN = 6) and Al^{3+} ($r = 0.535$ Å, CN = 6), and different position substitution result in different emission spectrum for diverse crystal field. When a small quantity of Mn^{4+} replaced Al^{3+} in the $\text{SrMgAl}_{10}\text{O}_{17}$ matrix,

the XRD patterns keep the original position without any shift, the experimental results

are shown in Fig.S2. (Dear Zhi Zhou, actually the shift of XRD pattern has no

meaning. This is because the shift depends on both cell parameters and zero shift of

the sample in the sample holder. I mean that even one powder can show absolutely

different shifts of peaks! You need just pack the sample slightly differently. So we

never should rely on pattern shift like many other persons make. The best way is to

refine cell parameters during Rietveld refinement and plot cell volume per

concentration – namely this is very precise information. By the way the sample shift

from the zero surface is also refined parameter and adjusted during Rietveld

refinement. In current manuscript we can: 1) leave current sentence and figure, if we

will have a problem we know how to improve it; 2) I can make quickly Rietveld

refinement and plot $V(x)$) With Ga^{3+} doping into the phosphor, the XRD curves

exhibited that samples change to complex phase gradually, as seen in Fig.1 (b). The

sample match well with the standard card of $\text{SrMgAl}_{10}\text{O}_{17}$ at first, then MgAl_2O_4 with

standard card of PDF#86-0094 appeared and its content gradually increased.

Concentrated on the sample when the doping content of Ga^{3+} is $y = 3$, its XRD pattern

mainly consisted of $\text{SrMgAl}_{10}\text{O}_{17}$ and MgAl_2O_4 , which noted as ● and ◆

respectively. With the further increase of Ga^{3+} dopant, the phase of samples are

mainly composed of SrMgAl₁₀O₁₇ host, XAl₂O₄ (X=Mg²⁺, Mn²⁺) and Ga₂O₃, what should be notice is that the latter three compound have similar XRD pattern with almost the same peak position.

3.2 Photoluminescence properties of SrMgAl_{10-y}Ga_yO₄:xMn⁴⁺ phosphors

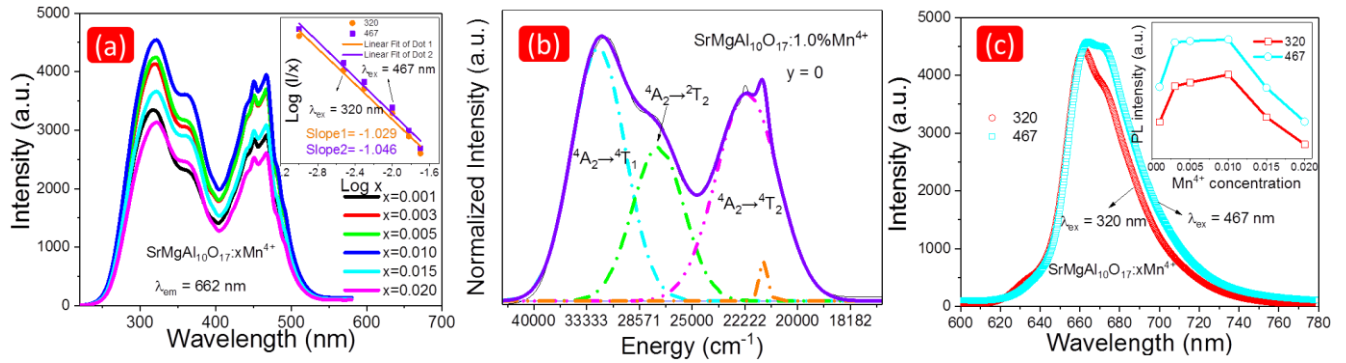


Fig. 2 (a) The photoluminescence excitation (PLE) spectra of SrMgAl₁₀O₁₇:xMn⁴⁺ (x=0.1%, 0.3%, 0.5%, 1.0%, 1.5%, 2.0%), inset is the dependence of log(I/x) versus log (x); (b) Gaussian fitting of SrMgAl₁₀O₁₇:1.0%Mn⁴⁺ sample; (c) The photoluminescence (PL) spectra of samples under the excitation of 320 nm and 467 nm respectively, inset is the tendency of emission intensity varies with Mn⁴⁺ doping concentration.

Fig.2 (a) and (c) exhibit the PLE ($\lambda_{em} = 661$ nm) and PL ($\lambda_{ex} = 320$ nm and $\lambda_{em} = 467$ nm) spectra of SrMgAl₁₀O₁₇:xMn⁴⁺ phosphors. It is obvious that the intensity of excitation and emission increased with the rising concentration of Mn⁴⁺ at first, both of them reached maximum when x = 1.0% then decreased with further more Mn⁴⁺ doping. In order to investigate the concentration quenching behavior of SrMgAl₁₀O₁₇:xMn⁴⁺ phosphor, the critical distance R_c needs to take into account, the value of R_c can be calculated by the following formula^{25, 26}:

$$R_c \approx 2 \left[\frac{3V}{4\pi x_c N} \right]^{1/3} \quad (1)$$

Where V , x_c and N stand for the volume of unit cell, the critical concentration of Mn⁴⁺

and the number of lattice sites can be occupied by Mn^{4+} , respectively. For $\text{SrMgAl}_{10}\text{O}_{17}:\text{xMn}^{4+}$ phosphor, the three values $V= 616.8 \text{ \AA}$, $x_c = 0.010$ and $N = 2$, accordingly the R_c is estimated to be 38.91 \AA . This value is much larger than 5 \AA which corresponding to the interaction between activator ions, therefore, the concentration quenching of $\text{SrMgAl}_{10}\text{O}_{17}:\text{xMn}^{4+}$ belongs to the multipolar-multipolar interaction.

The multipolar-multipolar interactions usually involve three types named dipole–dipole (d–d), dipole–quadrupole (d–q), and quadrupole–quadrupole (q–q) interactions, respectively. They refer to different value of θ in the following formula, which often used to reflect the interactions based on the Dexter’s theory^{27, 28}:

$$\frac{I}{x} = k[1 + \beta(x)^{\theta/3}]^{-1} \quad (2)$$

Where I and x mean the emission intensity and concentration of Mn^{4+} dopant, k and β are the same excitation condition and specific host crystal, and $\theta = 6, 8, 10$ refer to d–d, d–q, and q–q interactions, respectively.

The specific value of θ usually obtained by the slope of the dependence of $\log(I/x)$ versus $\log(x)$. From the inset of [Fig.2 \(a\)](#), the two fitting lines correspond to 320 nm and 467 nm wavelength excitation, two slopes are -1.029 and -1.046, respectively. The θ_1 and θ_2 calculated to be 3.087 and 3.138, both of them are close to 6 and indicated the concentration quenching mechanism of $\text{SrMgAl}_{10}\text{O}_{17}:\text{xMn}^{4+}$ phosphor is dipole–dipole (d–d) interaction.

The photoluminescence spectra of $\text{SrMgAl}_{10}\text{O}_{17}:1.0\%\text{Mn}^{4+}$ under 320 nm and 467 nm excitation in [Fig.2 \(c\)](#) show different forms that indicates two luminescence

centers. For investigating the change of excitation peaks, Gaussian fitting was done for the spectrum of $\text{SrMgAl}_{10}\text{O}_{17}:1.0\%\text{Mn}^{4+}$ sample. According to Fig.2 (b), this PLE spectrum was fitted into four Gaussian peaks located at 32154, 27247, 22123 and 21413 cm^{-1} , they are related to ${}^4\text{A}_2 \rightarrow {}^4\text{T}_1$, ${}^4\text{A}_2 \rightarrow {}^2\text{T}_2$ and ${}^4\text{A}_2 \rightarrow {}^4\text{T}_2$ transitions of Mn^{4+} , respectively.

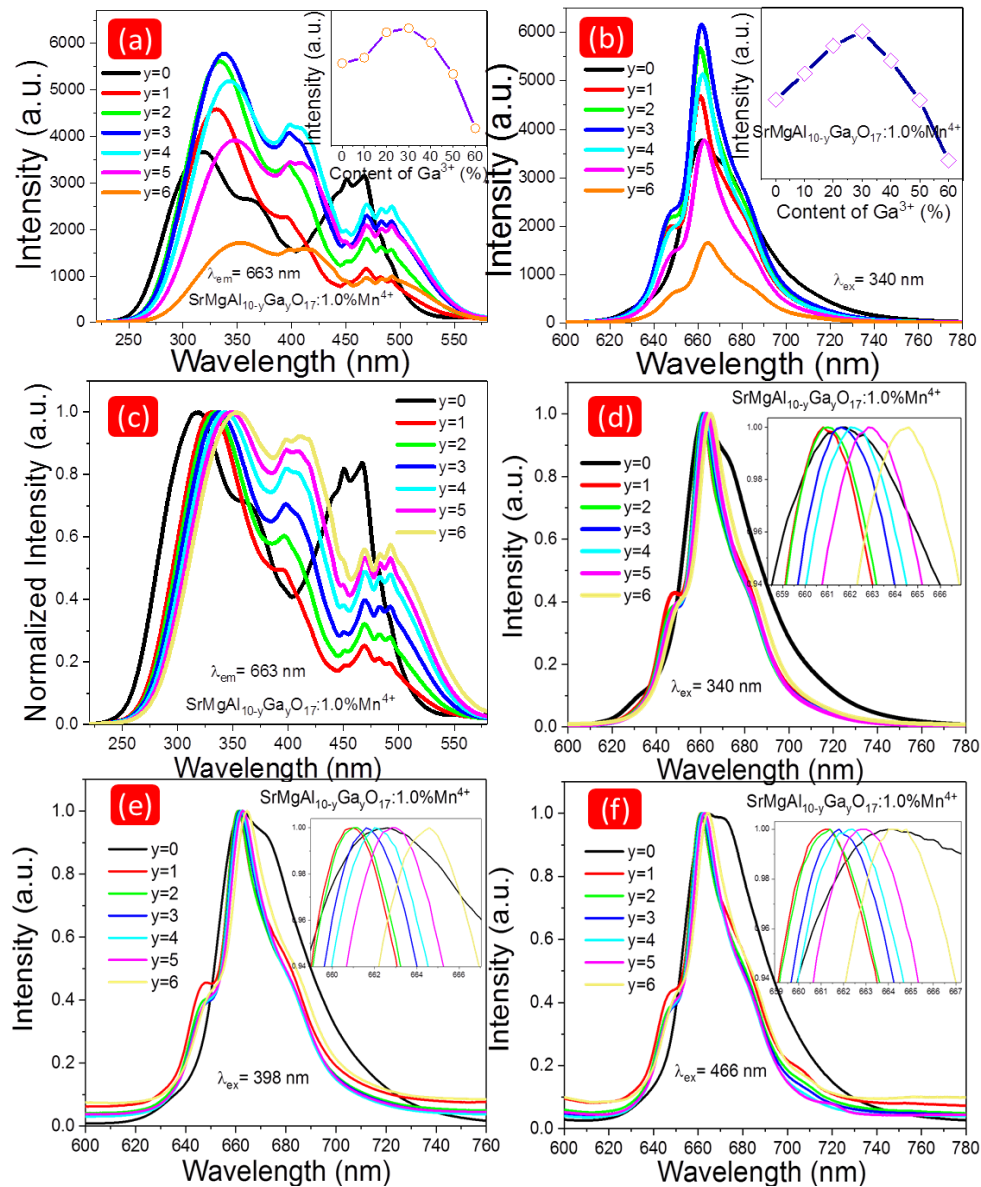


Fig.3 The (a) photoluminescence excitation and (b) photoluminescence spectra of $\text{SrMgAl}_{10-y}\text{Ga}_y\text{O}_{17}:1.0\%\text{Mn}^{4+}$ ($y=0, 1, 2, 3, 4, 5, 6$) phosphors; the normalized PLE spectra (c) monitored at 663 nm; the normalized PL spectra under (d) 340 nm, (e) 398 nm and (f) 466 nm excitation, insets are enlarged part of the peaks.

Series of SrMgAl_{10-y}Ga_yO₁₇:1.0%Mn⁴⁺ samples were obtained by selected the optimal doping concentration of Mn⁴⁺ at 1.0%, and their photoluminescence excitation and photoluminescence spectra are shown in Fig.3. The intensity of PLE and PL spectra both increasing with an incremental content of Ga³⁺ doping, they reach to the maximum when y = 3, after that show the trend of decrease with further more Ga³⁺ dopant. There is an interesting phenomenon, the normalized PLE spectra exhibit obvious red shift on each spectrum as shown in Fig.3 (c), for the ⁴A₂→²T₂ transitions show a great enhancement and red shift with the increase of Ga³⁺ doping. What's more, all PL spectra excited at different wavelength show slight red shift when the content of Ga³⁺ increasing.

Based on this situation, the change of crystal field is used to explain these phenomena. Crystal field parameters Dq , the Racah parameters B and C are three indexes to assess the effect of crystal field strength on the luminescent properties of Mn⁴⁺, the value of these parameters are calculated by the PLE and PL spectra. The Dq , B and C can be evaluated by the following equations^{29, 30}:

$$Dq = \frac{E(^4T_2 - ^4A_2)}{10} \quad (3)$$

$$\frac{Dq}{B} = \frac{15(x-8)}{(x^2-10x)} \quad (4)$$

$$x = \frac{E(^4A_2 - ^4T_1) - E(^4A_2 - ^4T_2)}{Dq} \quad (5)$$

$$\frac{E(^2E_g - ^4A_2)}{B} = \frac{3.05C}{B} + 7.9 - \frac{1.8B}{Dq} \quad (6)$$

According to Fig.2 (b), the energy of level of ⁴T₁, ⁴T₂ and ²E_g in SrMgAl₁₀O₁₇:1.0%Mn⁴⁺ are 32154, 22123 and 15082 cm⁻¹, its Dq , B and C are

calculated to be 2212, 1053 and 2561 cm^{-1} , and the value of Dq/B is 2.1, indicating that Mn^{4+} was exposed in a weak crystal field in $\text{SrMgAl}_{10}\text{O}_{17}$ matrix. However, the values of Dq/B are determined to be 2.22, 2.23, 2.24, 2.35, 2.43 and 2.49 with the Ga^{3+} dopant increasing from 10% to 60% which mean stronger crystal field ³¹, and this is the main reason for the red shift in luminescence spectra. The details of crystal field parameters and the energies states of $\text{SrMgAl}_{10-y}\text{Ga}_y\text{O}_{17}:1.0\%\text{Mn}^{4+}$ phosphors are shown in Table 1.

Table 1 Crystal Field Parameters and Energy States in $\text{SrMgAl}_{10-y}\text{Ga}_y\text{O}_{17}:1.0\%\text{Mn}^{4+}$ phosphors

Sample	D_q/B	D_q	B	C	${}^4\text{A}_2 \rightarrow {}^4\text{T}_1$ (cm^{-1})	${}^4\text{A}_2 \rightarrow {}^4\text{T}_2$ (cm^{-1})	${}^2\text{E} \rightarrow {}^4\text{A}_2$ (cm^{-1})
y=0	2.10	2212	1055	2561	32154	22124	15110
y=1	2.22	2110	951	2797	30303	21097	15133
y=2	2.23	2088	935	2833	29940	20877	15129
y=3	2.24	2070	924	2852	29674	20704	15115
y=4	2.35	2062	876	2952	29240	20619	15106
y=5	2.43	2058	847	3008	28986	20576	15088
y=6	2.49	2045	821	3051	28653	20450	15047

Fig.4 (a) show the diffuse reflection spectra of these powder samples, it is obvious that the reflection rate decreased gradually with an increasing content of Ga^{3+} , which has the same trend as the change of photoluminescence excitation spectra. All diffuse reflection curves can be divided to four part corresponding to the absorption of matrix and ${}^4\text{A}_2 \rightarrow {}^4\text{T}_1$, ${}^4\text{A}_2 \rightarrow {}^2\text{T}_2$, ${}^4\text{A}_2 \rightarrow {}^4\text{T}_2$ transitions of Mn^{4+} , respectively. It is consistent with the Gaussian fitting of PLE spectrum. The diffuse reflection spectra can be translated into UV-vis absorption spectra, and get the band gap energies further through the following equation ^{32,33}:

$$(ahv)^n = A(hv - E_g) \quad (7)$$

where α and A are the absorption coefficient and proportional constant, $h\nu$ and E_g refer to the photon energy and the band gap, respectively. Two values of n are 2 and 1/2 means direct and indirect transition materials, respectively. The band gap energy of this series sample exhibits an upward and then a downward trend that increase from 5.25 eV to 5.44 eV then drop down to 5.21 eV, as shown in Fig.4 (b).

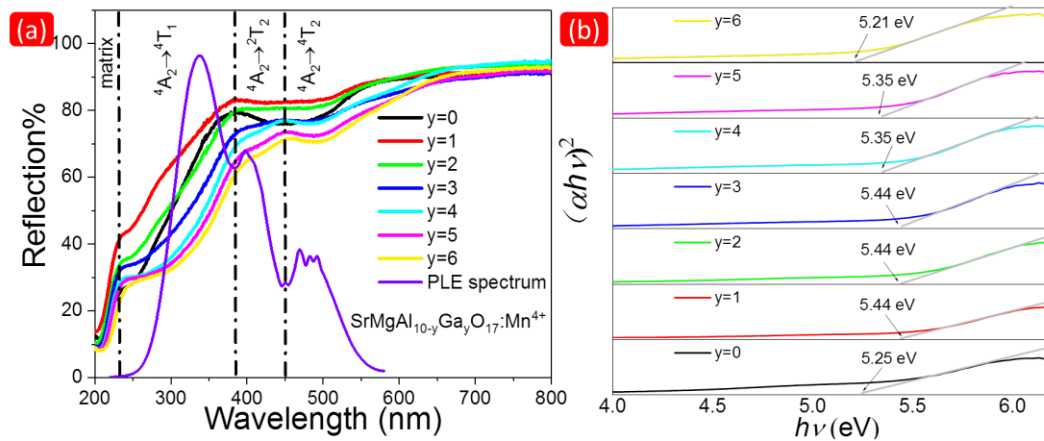


Fig.4 (a) The diffuse reflection spectra of $\text{SrMgAl}_{10-y}\text{Ga}_y\text{O}_{17}:1.0\%\text{Mn}^{4+}$ phosphors and one PLE spectrum of $\text{SrMgAl}_7\text{Ga}_3\text{O}_{17}:1.0\%\text{Mn}^{4+}$ sample; (b) corresponding band gap energy fitting.

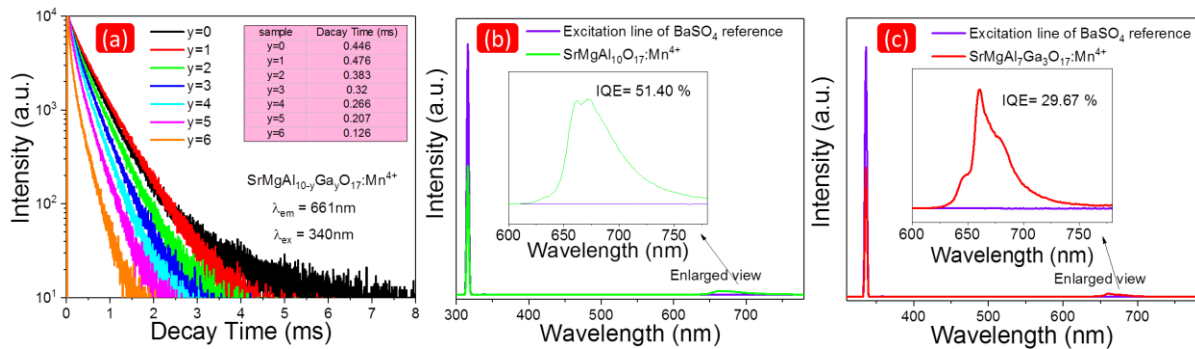


Fig.5 (a) The lifetime decay curves of $\text{SrMgAl}_{10-y}\text{Ga}_y\text{O}_{17}: \text{Mn}^{4+}$ phosphors monitored at 661 nm; the measurement of quantum efficiency of (b) $\text{SrMgAl}_{10}\text{O}_{17}: \text{Mn}^{4+}$ and (c) $\text{SrMgAl}_7\text{Ga}_3\text{O}_{17}: \text{Mn}^{4+}$, the insets are the enlarged pattern range from 600 nm to 780 nm.

In order to investigate the luminescence kinetics of $\text{SrMgAl}_{10-y}\text{Ga}_y\text{O}_{17}: \text{Mn}^{4+}$ phosphor, the lifetime of these samples were measured and display in Fig.5 (a). All of

these curves fitting well with the double-exponential decay model, its expression is shown below³⁴:

$$I(t) = I_0 + C_1 \exp(-t/\tau_1) + C_2 \exp(-t/\tau_2) \quad (8)$$

And the average life time can be further calculated as³⁵:

$$t = \frac{C_1\tau_1^2 + C_2\tau_2^2}{C_1\tau_1 + C_2\tau_2} \quad (9)$$

where I and I_0 stand for the photoluminescence intensity at time t and time 0, C_1 and C_2 refer to pre-exponential factors, τ_1 and τ_2 are the lifetime components, respectively. The lifetime of SrMgAl_{10-y}Ga_yO₁₇: Mn⁴⁺ was calculated to be 0.446, 0.476, 0.383, 0.320, 0.266, 0.207 and 0.126 ms when the Ga³⁺ doping from 0 to 60%. The double-exponential decay model indicates that Mn⁴⁺ should have two luminescence centers in SrMgAl_{10-y}Ga_yO₁₇ matrix, which is consistent with the emission spectrum.

Quantum efficiency is an important parameter to evaluate luminescence property of phosphors, the experimental QE of SrMgAl₁₀O₁₇: Mn⁴⁺ and SrMgAl₇Ga₃O₁₇: Mn⁴⁺ samples are shown in Fig.5 (b) and (c), which can be calculated via the following formula^{36,37}:

$$\eta = \frac{\int L_S}{\int E_R - \int E_S} \quad (10)$$

herein, η is internal quantum efficiency, L_S stands for the emission spectra of the sample, E_S and E_R are the reflection of excitation light with and without sample, respectively. The IQE of SrMgAl₁₀O₁₇: Mn⁴⁺ and SrMgAl₇Ga₃O₁₇: Mn⁴⁺ are determined to be 51.40% and 29.67%. It is interesting that SrMgAl₇Ga₃O₁₇: Mn⁴⁺ with lower quantum efficiency exhibit stronger luminescence emission than SrMgAl₁₀O₁₇: Mn⁴⁺ sample, indicating SrMgAl₇Ga₃O₁₇: Mn⁴⁺ has more potential for

luminescence with further optimizing process.

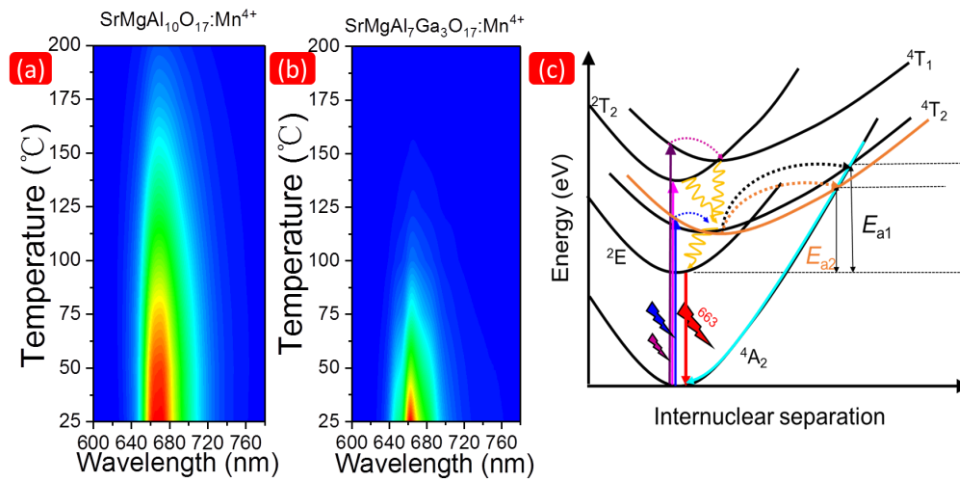


Fig.6 The temperature-dependence luminescence spectrum of (a) $\text{SrMgAl}_{10}\text{O}_{17}:\text{Mn}^{4+}$ and (b) $\text{SrMgAl}_7\text{Ga}_3\text{O}_{17}:\text{Mn}^{4+}$; (c) configurational coordinate diagram for Mn^{4+} ions in $\text{SrMgAl}_{10-y}\text{Ga}_y\text{O}_{17}$ phosphor.

The thermal stability of phosphor is evaluated by the temperature-dependence luminescence spectra which shown in Fig.6 (a) and (b). The emission intensity decreases rapidly as the temperature increases in both the two samples, and decline trend is more serious in $\text{SrMgAl}_7\text{Ga}_3\text{O}_{17}:\text{Mn}^{4+}$ phosphor. This result showed that Ga^{3+} doping could have destroyed the stability of matrix structure to some extent and caused to lower activation energy. It further promotes the loss of energy with non-radiative processes and resulted in worse thermal stability.

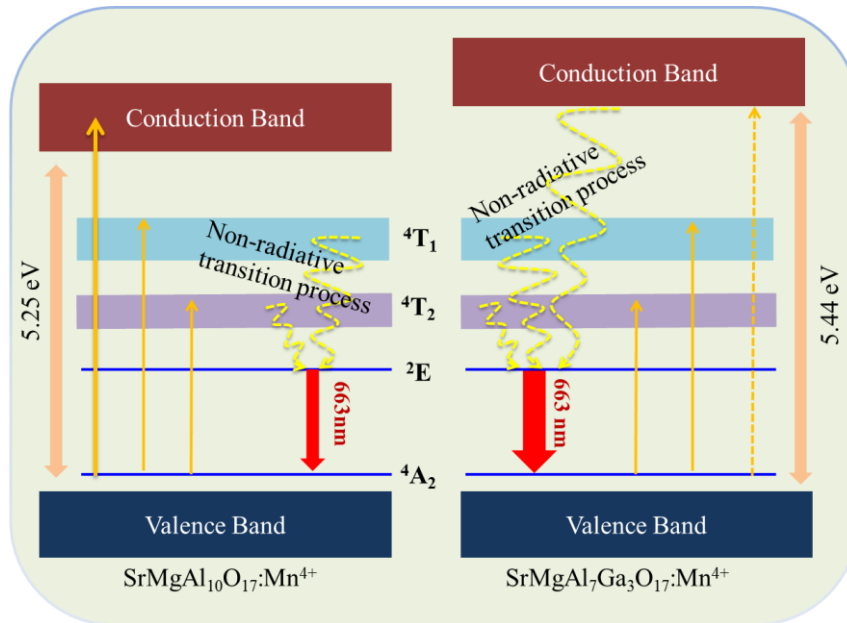


Fig.7 Mechanism diagram of luminescence in $\text{SrMgAl}_{10-y}\text{Ga}_y\text{O}_{17}:\text{Mn}^{4+}$ phosphor.

Fig. 7 shows the mechanism diagram in $\text{SrMgAl}_{10-y}\text{Ga}_y\text{O}_{17}:\text{Mn}^{4+}$ for clearly describing the energy transition process. There is only Mn^{4+} ion transition luminescence in the sample phosphors, Mn^{4+} is excited from $^4\text{A}_2$ energy level to $^4\text{T}_1$, $^4\text{T}_2$ even conduction band, then drop to $^2\text{E}_g$ level through non-radiative transition process, final relax to $^4\text{A}_2$ level with bright red emission. The value of band-gap has an effect on energy transfer, excited electron often trapped by the conduction band and result in quenching directly with a narrow band-gap in $\text{SrMgAl}_{10}\text{O}_{17}:\text{Mn}^{4+}$ phosphor. On the contrary, $\text{SrMgAl}_7\text{Ga}_3\text{O}_{17}:\text{Mn}^{4+}$ sample have wider band gap, so it is more difficult for excited ion jump into conduction band. This situation reduces the energy loss and more energy was using for photoluminescence, which is consistent with the experiment results.

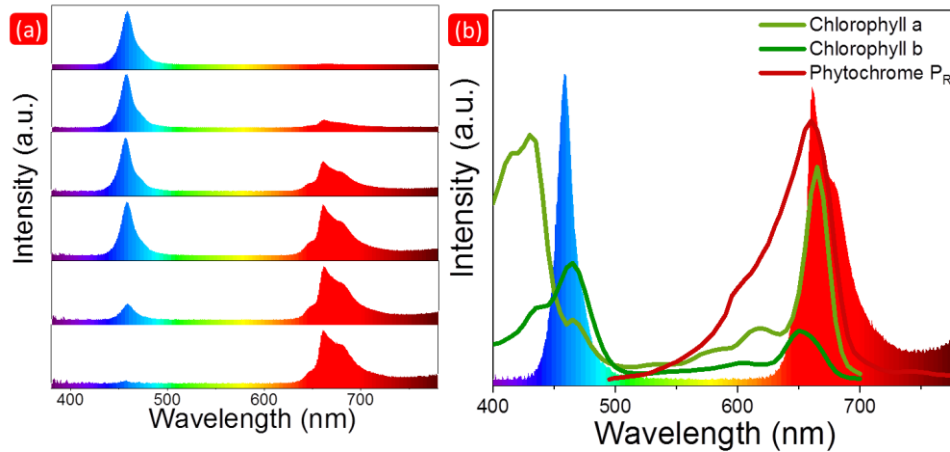


Fig.8 (a) Electro-luminescent spectra of the fabricated LEDs combined with 470 nm blue chip and different contents of $\text{SrMgAl}_7\text{Ga}_3\text{O}_{17}:\text{Mn}^{4+}$ sample; (c) the comprehensive comparison between EL spectra and the absorption curves of the plant pigments of Chlorophyll A, B and Phytochrome P_R .

In order to investigate the potential application of $\text{SrMgAl}_{10-y}\text{Ga}_y\text{O}_{17}:\text{Mn}^{4+}$ phosphor, LED devices were fabricated with 470 nm blue chips and different content of the as-obtained $\text{SrMgAl}_7\text{Ga}_3\text{O}_{17}:\text{Mn}^{4+}$ sample, their electro-luminescent spectra are shown in Fig.8. The red emission continue rising with the increasing content of phosphor, indicate the ratio of blue and red light can be easily adjust to adapt the needs of different plants growth. The electroluminescent spectrum of the fabricated red-emitting LED is mainly composed by blue band (420-500 nm) and red band (650-750 nm) with peak at 470 nm and 663 nm, which can fit the absorption spectra of plant pigment including chlorophyll A, chlorophyll B and phytochrome P_R well, indicate the $\text{SrMgAl}_{10-y}\text{Ga}_y\text{O}_{17}:\text{Mn}^{4+}$ phosphors have potential to be a candidate in LED plant growth LED lights.

4. Conclusion

In this work, series of Ga³⁺-doped SrMgAl₁₀O₁₇: Mn⁴⁺ phosphors with enhanced luminescence properties were synthesized through high temperature approach. The Ga³⁺ dopants improve the luminescent intensity by 163% and cause the red shift in all photoluminescence excitation (PLE) and photoluminescence (PL) spectra and crystal field theory is using to explain the red shift phenomenon. All samples have a broad band of excitation spectra range from 220 to 580 nm indicate they can be excited by both near ultraviolet and blue chips. The phosphors exhibit bright red emission located at 663 nm corresponding to ²E_g→⁴A₂ transition of Mn⁴⁺. The Ga³⁺ doping increase the band gap of SrMgAl₇Ga₃O₁₇: Mn⁴⁺ sample to reduce non-radiative transitions and improve the emission intensity while it has worse thermal stability for its low activation energy. Devices assembled with blue chip and the as-obtained SrMgAl₇Ga₃O₁₇: Mn⁴⁺ phosphor emit bright blue and red light which match the plant absorption spectra well, indicating the SrMgAl_{10-y}Ga_yO₁₇: Mn⁴⁺ phosphor have potential application on plant growth LED lighting.

Conflicts of interest

There are no conflicts to declare.

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